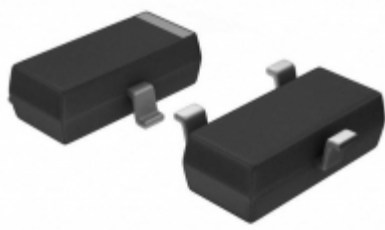






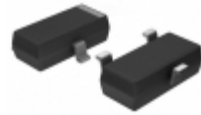

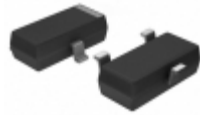
	FJV3102RMTF	
	Hersteller-Teilenummer:	FJV3102RMTF
	Hersteller / Marke:	Fairchild/ON Semiconductor
	Teil der Beschreibung:	TRANS PREBIAS NPN 0.2W SOT23-3
	Datenblätter:	1.FJV3102RMTF.pdf 2.FJV3102RMTF.pdf
	RoHs Status:	Bleifrei / RoHS-konform
Lagerzustand:	New original, 42941 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	FJV3102RMTF
Hersteller	Fairchild/ON Semiconductor
Beschreibung	TRANS PREBIAS NPN 0.2W SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	42941 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	30 @ 5mA, 5V
Frequenz - Übergang	250MHz
Widerstand - Base (R1) (Ohm)	10k
Widerstand - Emitter-Basis (R2) (Ohm)	10k
Verpackung	Original-Reel®

FJV3102RMTF ist neu im Original, Suche FJV3102RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3102RMTF Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3102RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 FJV3103RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3101RLIMTF FAIRCHILD FJV3101RLIMTF FAIRCHILD	 FJV3103RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3101RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3
 FJV3102RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 0.2W SOT23-3	 FJV3101RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3104RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3104RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3

heiße Teile

Mehr

⊗ FJV1845EMTF	↔ FJV1845EMTF	⇒ FJV1845FMTF	D FJV1845FMTF	↕ FJV1845PMTF
⊣ FJV1845PMTF	⊗ FJV1845UMTF	D FJV1845UMTF	⇒ FJV3101RLIMTF	↕ FJV3101RMTF
⊗ FJV3101RMTF	⊣ FJV3102RMTF	⊗ FJV3103RMTF	↔ FJV3103RMTF	↕ FJV3104RMTF
D FJV3104RMTF	⊗ FJV3105RMTF	⊣ FJV3105RMTF	⊗ FJV3106RMTF	↕ FJV3106RMTF
⇒ FJV3107RMTF	↔ FJV3107RMTF	⊗ FJV3108RMTF	⊣ FJV3108RMTF	↕ FJV3109R
↔ FJV3109RMTF	⇒ FJV3109RMTF	D FJV3110RMTF	⊗ FJV3110RMTF	⊣ FJV3111RMTF
⊗ FJV3111RMTF	D FJV3112RMTF	⇒ FJV3112RMTF	↔ FJV3113RMTF	↕ FJV3113RMTF
⊣ FJV3114RMTF	⊗ FJV3114RMTF	↔ FJV3115RMTF	⇒ FJV3115RMTF	↕ FJV4101RMTF
⊗ FJV4101RMTF	⊣ FJV4102RLIMTF	⊗ FJV4102RMTF	D FJV4102RMTF	↕ FJV4103RMTF
↔ FJV4103RMTF	⊗ FJV4104RMTF	⊣ FJV4104RMTF	⊗ FJV4105RMTF	↕ FJV4105RMTF

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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